

# N-Channel 60-V (D-S) MOSFET

#### **Features**

- Low rDS(on) trench technology
- · Fast switching speed
- · Low thermal impedance
- · RoHS compliant package

#### **Applications:**

- · Power Routing
- · Li Ion Battery Packs
- · Level Shifting and Driver Circuits

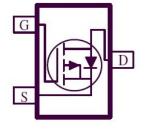
#### **Packing & Order Information**

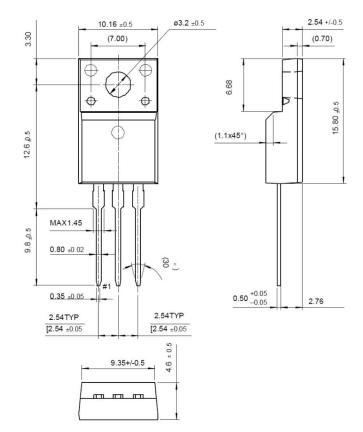
3,000/Reel



RoHS COMPLIANT

#### **Graphic symbol**







# N-Channel 60-V (D-S) MOSFET

### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings (T <sub>A</sub> =25°C unless otherwise specified)						
Symbol	Parameter	Value	Unit			
$V_{DS}$	Drain-Source Voltage	60	V			
V <sub>GS</sub>	Gate-Source Voltage	±20	V			
I <sub>D</sub>	Continuous Drain Current <sup>a</sup> (T <sub>A</sub> =25°C) 90		А			
I <sub>DM</sub>	Pulsed Drain Current <sup>a</sup>	360	А			
I <sub>S</sub>	Continuous Source Current (Diode Conduction) <sup>a</sup>	90	А			
P <sub>D</sub>	Power Dissipation <sup>a</sup> (T <sub>A</sub> =25°C)	300	W			
T <sub>J</sub> /T <sub>STG</sub>	Operating Junction and Storage Temperature	-55 to +175	°C			

Thermal Resistance Ratings						
Symbol	Parameter	Maximum	Units			
$R_{ heta JA}$	Maximum Junction-to-Ambient <sup>a</sup>	62.5	°C/W			
$R_{\theta JC}$	Maximum Junction-to-Case	1	C/VV			

#### **Notes**

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

Static						
Symbol	Parameter	Test Conditions	Min	Тур.	Max.	Units
$V_{GS}$	Gate Threshold Voltage	$V_{DS} = V_{GS}$ , $I_D = -250 \mu A$	1			V
I <sub>GSS</sub>	Gate-Body Leakage	$V_{DS} = 0 \text{ V}$ , $V_{GS} = \pm 20 \text{ V}$			±100	nA
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	$V_{DS} = 48 \text{ V}, V_{GS} = 0 \text{ V}$ $V_{DS} = 48 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			1 25	uA
I <sub>D(on)</sub>	On-State Drain Current	V <sub>DS</sub> = 5 V, V <sub>GS</sub> = 10 V	120			Α
R <sub>DS(on)</sub>	Drain-Source On-Resistance	$V_{GS} = 10 \text{ V}, I_D = 45 \text{ A}$ $V_{GS} = 5.5 \text{ V}, I_D = 44 \text{ A}$			3 4	mΩ
g <sub>fs</sub>	Forward Tranconductance	V <sub>DS</sub> = 15 V , I <sub>D</sub> = 20 A		35		S
V <sub>SD</sub>	Diode Forward Voltage	I <sub>S</sub> = 45 V , V <sub>GS</sub> = 0 V		0.84		V

Dynamic <sup>b</sup>						
Symbol	Parameter	Test Conditions	Min	Тур.	Max.	Units
$t_{d(on)}$	Turn-On Delay Time	$V_{DS} = 30 \text{ V}$ , $R_L = 1.5 \Omega$ , $V_{GEN} = 10 \text{ V}$ , $R_{GEN} = 6 \Omega$ $I_D = 20 \text{ A}$		64		ns
t <sub>r</sub>	Rise Time			112		ns
t <sub>d(off)</sub>	Turn-Off Delay Time			276		ns
tf	Fall Time			86		ns



# N-Channel 60-V (D-S) MOSFET

Dynamic <sup>b</sup>						
Symbol	Parameter	Test Conditions	Min	Тур.	Max.	Units
$Q_g$	Total Gate Charge	$V_{DS} = 30 \text{ V}, I_{D} = 20 \text{ A}$ $V_{GS} = 5.5 \text{ V}$		161		nC
Q <sub>gs</sub>	Gate-Source Charge			58		nC
$Q_{gd}$	Gate-Drain Charge			82		nC
C <sub>ISS</sub>	Input Capacitance	$V_{GS} = 0 \text{ V}$ , $V_{DS} = 15 \text{ V}$ , $f = 1\text{MHz}$		33061		pF
Coss	Output Capacitance			1181		pF
C <sub>RSS</sub>	Reverse Transfer Capacitance			1135		pF

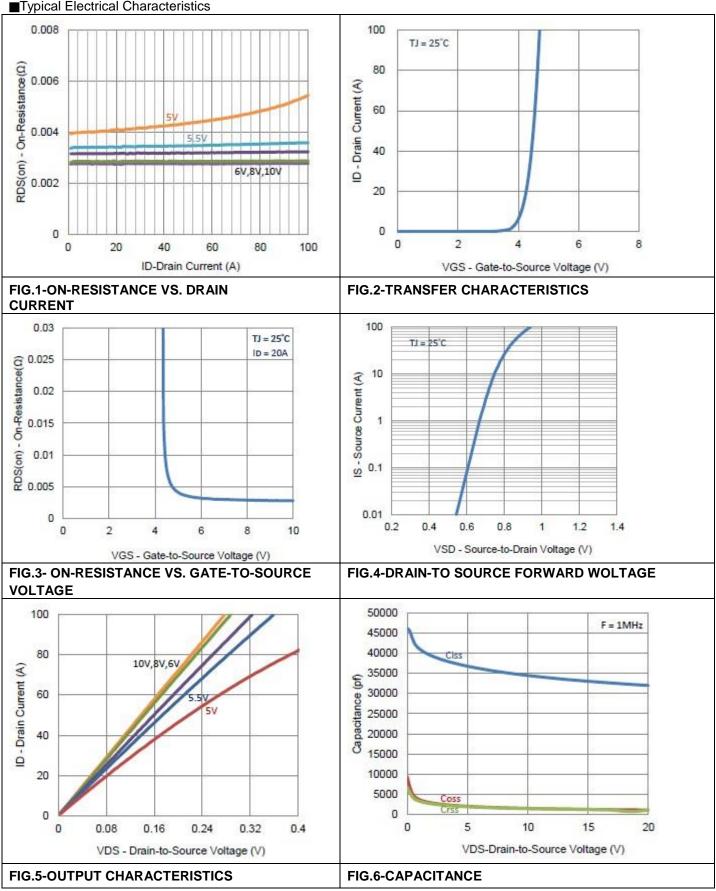
#### **Notes**

- a. Pulse test: PW <= 300us duty cycle <= 2%.
- b. Guaranteed by design, not subject to production testing.



## N-Channel 60-V (D-S) MOSFET

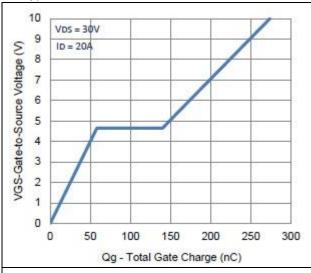
■Typical Electrical Characteristics





## N-Channel 60-V (D-S) MOSFET

#### ■Typical Electrical Characteristics



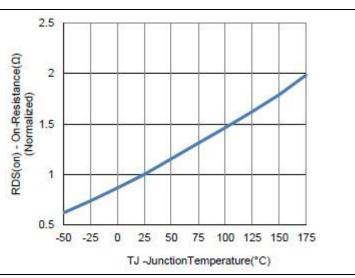


FIG.7-GATE CHARGE

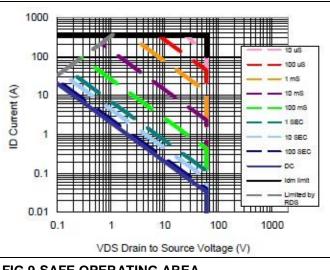


FIG.8-NORMALIZED ON-RESISTANCE VS JUNCTION TEMPERATURE

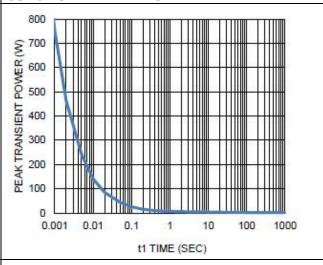


FIG.9-SAFE OPERATING AREA



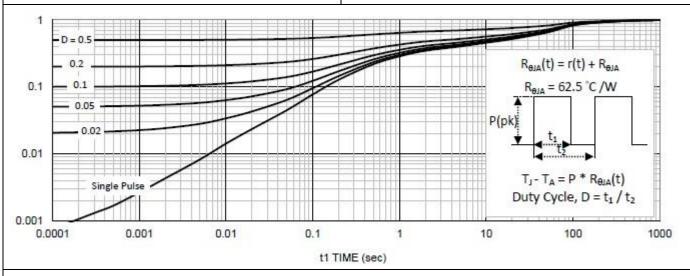


FIG.11-NORMALIZED THERMAL TRANSIENT JUNCTION TO AMBIENT



N-Channel 60-V (D-S) MOSFET

#### laimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE. Bruckewell Technology Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Bruckewell"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product. Bruckewell makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Bruckewell disclaims

- (i) Any and all liability arising out of the application or use of any product.
- (ii) Any and all liability, including without limitation special, consequential or incidental damages.
- (iii) Any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Bruckewell's knowledge of typical requirements that are often placed on Bruckewell products in generic applications.

Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time.

Product specifications do not expand or otherwise modify Bruckewell's terms and conditions of purchase, including but not limited to the warranty expressed therein.